



App. No. 09/653,156

#17C  
Amdt  
SDavis  
3/5/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. ....09/653,156  
Filing Date .....August 31, 2000  
Inventor..... Vishnu K. Agarwal, et al  
Assignee..... Micron Technology, Inc.  
Group Art Unit.....2813  
Examiner ..... Y. Huynh  
Attorney's Docket No. ....MI22-1518  
Title: Enhanced Surface Area Capacitor Fabrication Methods (as amended)

**RESPONSE TO OCTOBER 15, 2002 OFFICE ACTION**

To: Art Unit 2813  
Assistant Commissioner for Patents  
Washington, D.C. 20231

From: James E. Lake (Tel. 509-624-4276; Fax 509-838-3424)  
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**AMENDMENTS**

**In the Specification**

Please replace the title with the following clean replacement title in accordance  
with 37 C.F.R. §1.121(b)(1)(ii):

--Enhanced Surface Area Capacitor Fabrication Methods--

**In the Claims**

Please add new claim 27 in accordance with 37 C.F.R. 1.121(c)(1)(i). No marked up  
version is required.

C1 SUB DI 17  
17. (new) The method of claim 1 wherein the TiN forms a continuous layer within the  
first electrode.

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